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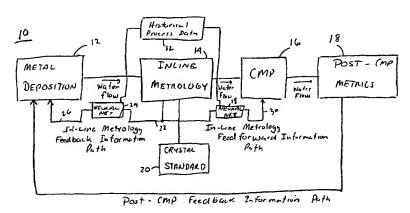
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[Continued on next page]

(54) Title: FEEDFORWARD AND FEEDBACK CONTROL OF SEMICONDUCTOR FABRICATION PROCESS USING SEC-ONDARY ELECTRON MICROSCOPY AND A FOCUSED ION BEAM SYSTEM



(57) Abstract: A system (70) for crystallography including a sample holder (74), an electron source (76) for generating an electron beam, and a scanning actuator (80) for controlling the relative movement between the electron beam and the crystalline sample, the scanning actuator being controllable for directing the electron beam at a series of spaced apart points within the sample area. The system also includes an image processor (84) for generating crystallographic data based upon electron diffraction from the crystalline sample and for determining whether sufficient data have been acquired to characterize the sample area. The system further includes a controller (86) for controlling the scanning actuator to space the points apart such that acquired data is representative of a different grains within the crystalline sample. In other embodiments, the invention includes one or more ion beams (178, 188) for crystallography and a combination ion beam/electron beam (218, 228). Crystallographic metrology data may bai grain size and orientation which are feedback and feed-forwarded to a deposition station (such as a CVD station) and to a chemical-mechanical planarization station respectively for in-line control of the fabrication process of a semiconductor.





For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

INTERNATIONAL SEARCH REPORT

nal Application No Inter PCT/US 03/07264

A. CLASSIFICATION OF SUBJECT MATTER IPC 7 G01N23/225 G01N23/203 H01L21/66

According to international Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols) IPC 7 G01N H01L

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practical, search terms used)

EPO-Internal, WPI Data, PAJ, INSPEC, COMPENDEX

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X Further documents are listed in the continuation of box C.	X Patent family members are listed in annex.		
"A" document defining the general state of the art which is not considered to be of particular relevance "E" earlier document but published on or after the international filling date "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "O" document referring to an oral disclosure, use, exhibition or other means "P" document published prior to the international filing date but later than the priority date claimed	"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art. "8" document member of the same patent family		
Date of the actual completion of the international search	Date of mailing of the International search report		
4 November 2003	02.04.2004		
Name and mailing address of the ISA European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3016	Authorized officer Huenges, A		

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Interr 11 Aprication No PCT/US 03/07264

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Citation of cocument, with indication, more appropriate		
EL CHEMALI C AND AL: "Multizone uniformity control of a chemical mechanical polishing process utilizing a pre- and postmeasurement strategy" JOURNAL OF VACUUM SCIENCE AND TECHNOLOGY: PART A, AMERICAN INSTITUTE OF PHYSICS. NEW YORK, US, vol. 18, no. 4, pt 1-2, July 2000 (2000-07), pages 1287-1296, XP002217674 ISSN: 0734-2101 page 1289	4,5	
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International application No. PCT/US 03/07264

Box I Observations where certain claims were found unsearchable (Continuation of item 1 of first sheet)
This International Search Report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:
1. Claims Nos.: because they relate to subject matter not required to be searched by this Authority, namely:
2. Claims Nos.: because they relate to parts of the International Application that do not comply with the prescribed requirements to such an extent that no meaningful International Search can be carried out, specifically:
3. Claims Nos.: because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).
Box II Observations where unity of invention is lacking (Continuation of item 2 of first sheet)
This International Searching Authority found multiple inventions in this international application, as follows:
see additional sheet
As all required additional search fees were timely paid by the applicant, this International Search Report covers all searchable claims.
2. As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.
3. As only some of the required additional search fees were timely paid by the applicant, this International Search Report covers only those claims for which fees were paid, specifically claims Nos.:
4. No required additional search fees were timely paid by the applicant. Consequently, this International Search Report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.: 1-7, 30-37
Remark on Protest The additional search fees were accompanied by the applicant's protest. No protest accompanied the payment of additional search fees.

INTERNATIONAL SEARCH REPORT

International Application No. PCT/US 03/07264

FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

This International Searching Authority found multiple (groups of) inventions in this international application, as follows:

1. claims: 1-7,30-37

Scanning electron microscope (SEM) adapted to generate crystallographic data from different grains within the crystalline sample; method of using the apparatus.

2. claims: 8-14,38-49

Focused ion beam (FIB) apparatus adapted to provide a contrast image; method of using the apparatus.

3. claims: 15-22,50-60

Combined SEM and FIB apparatus adapted to provide a contrast image and crystallographic data from different grains within the sample; method of using the apparat.

4. claims: 23-29

Crystallographic standard sample for ion channeling analysis of a crystalline sample.



Interi inal Application No PCT/US 03/07264

Information on patent family members

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